



DMN6013LFGQ

60V N-CHANNEL ENHANCEMENT MODE MOSFET PowerDI3333-8

## **Product Summary**

BV <sub>DSS</sub>	R <sub>DS(ON)</sub> max	I <sub>D</sub> max T <sub>A</sub> = +25°C
001/	13mΩ @ $V_{GS}$ = 10V	10.3A
60V	18mΩ @ V <sub>GS</sub> = 4.5V	8.8A

# **Description and Applications**

This MOSFET is designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP, and is ideal for use in:

- Motor control
- DC to DC converters
- Reverse polarity protection

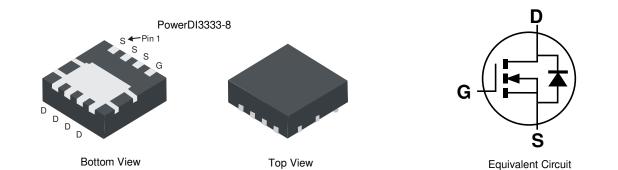
### **Features and Benefits**

- Low R<sub>DS(ON)</sub> Ensures on state losses are minimized
- Small form factor thermally efficient package enables higher density end products
- Occupies just 33% of the board area occupied by SO-8 enabling smaller end product
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DMN6013LFGQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/guality/product-definitions/

### **Mechanical Data**

- Package: PowerDl<sup>®</sup>3333-8
- Package Material: Molded Plastic, "Green" Molding Compound, UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminals: Finish—Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.072 grams (Approximate)



### Ordering Information (Note 4)

Orderable Part Number	Baakaga	Packing			
Orderable Part Number	Package	Quantity	Carrier		
DMN6013LFGQ-7	PowerDI3333-8	2,000	Tape & Reel		
DMN6013LFGQ-13	PowerDI3333-8	3,000	Tape & Reel		

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

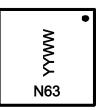
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.



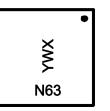
## **Marking Information**

Site1



N63 = Product Type Marking Code YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 23 = 2023) WW = Week Code (01 to 53)

Site2:



N63 = Product Type Marking Code YWX = Date Code Marking Y = Year (ex: 3 = 2023) W = Week (ex: a = Week 27, z Represents Week 52 and 53) X = Internal Code (ex: U = Monday)

Date Code Key

Year	2023	2024	2025	2026	2027	2028	2029	2030	2031	2032	2033	2034
Code	3	4	5	6	7	8	9	0	1	2	3	4
Week 1-26			27-52				53					
Code	A-Z			a-z			Z					
Internal Code	Sun Mon			Tue	1	Ned	Thu	1	Fri		Sat	
Code	7	Γ	U		V		W	Х		Y		Ζ

#### **Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Drain-Source Voltage		V <sub>DSS</sub>	60	V
Gate-Source Voltage		V <sub>GSS</sub>	±20	V
Operation on the Discount (Marta C) \/ 10\/	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	ID	10.3 8.3	А
Continuous Drain Current (Note 6) $V_{GS} = 10V$	$T_{C} = +25^{\circ}C$ $T_{C} = +100^{\circ}C$	ID	45 28	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)		I <sub>DM</sub>	58.3	А
Maximum Continuous Body Diode Forward Current (Note 6)		Is	3	А
Avalanche Current, L = 0.1mH		las	33.3	А
Avalanche Energy, L = 0.1mH		E <sub>AS</sub>	56.8	mJ

# Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)	PD	1	W	
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	D	123	°C/W
Thermal Resistance, Junction to Amblent (Note 5)	t < 10s	$R_{ heta JA}$	69	0/14
Total Power Dissipation (Note 6)		PD	2.1	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	D	60	°C/W
Thermal Resistance, Junction to Ambient (Note 6)	t < 10s	$R_{ heta JA}$	34	0/14
Total Power Dissipation (Note 6)		PD	40	W
Thermal Resistance, Junction to Case (Note 6)	$R_{\theta JC}$	3.2	°C/W	
Operating and Storage Temperature Range		T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

 Notes:
 5. Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.

 6. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.



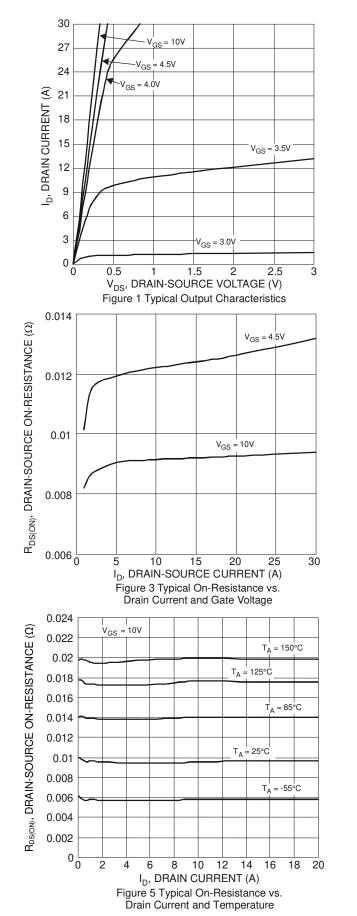
# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

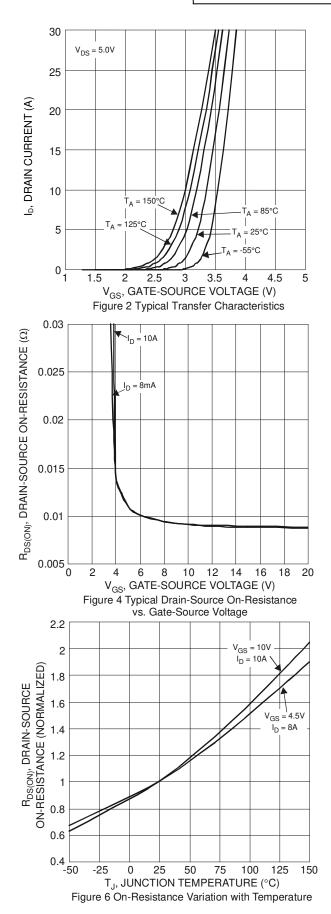
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	60	—		V	$V_{GS} = 0V, I_D = 250\mu A$
Zero Gate Voltage Drain Current, TJ = +25°C	IDSS		—	1	μΑ	$V_{DS} = 60V, V_{GS} = 0V$
Gate-Source Leakage	IGSS	_	—	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)	<u> </u>					
Gate Threshold Voltage	V <sub>GS(TH)</sub>	1	1.8	3	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$
Static Drain-Source On-Resistance	Descent	_	9.3	13	mΩ	$V_{GS} = 10V, I_D = 10A$
	R <sub>DS(ON)</sub>	_	12.3	18	11152	$V_{GS} = 4.5V, I_D = 8A$
Diode Forward Voltage	V <sub>SD</sub>		0.7	1.2	V	$V_{GS} = 0V, I_{S} = 1.7A$
DYNAMIC CHARACTERISTICS (Note 8)	<u> </u>					
Input Capacitance	C <sub>iss</sub>	_	2577	_	pF	V 20V V 0V
Output Capacitance	Coss	_	162	_	pF	$-V_{DS} = 30V, V_{GS} = 0V,$ -f = 1MHz
Reverse Transfer Capacitance	C <sub>rss</sub>	_	132	_	pF	
Gate Resistance	Rg		0.9		Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$
Total Gate Charge (V <sub>GS</sub> = 4.5V)	Qg	_	26.6	_	nC	
Total Gate Charge (V <sub>GS</sub> = 10V)	Qg	_	55.4	_	nC	V 20V/ 1 10A
Gate-Source Charge	Q <sub>gs</sub>		9.3		nC	$-V_{DS} = 30V, I_{D} = 10A$
Gate-Drain Charge	Q <sub>gd</sub>		12.6		nC	
Turn-On Delay Time	t <sub>D(ON)</sub>		6.2		ns	
Turn-On Rise Time	t <sub>R</sub>		9.9		ns	$V_{GS} = 10V, V_{DS} = 30V,$
Turn-Off Delay Time	t <sub>D(OFF)</sub>	_	27.6		ns	$R_G = 3\Omega$ , $I_D = 10A$
Turn-Off Fall Time	t <sub>F</sub>	_	11.7		ns	1
Body Diode Reverse Recovery Time	t <sub>RR</sub>	_	9.4		ns	
Body Diode Reverse Recovery Charge	Q <sub>RR</sub>		18.6		nC	I <sub>F</sub> = 10A, di/dt = 100A/µs

Notes:7. Short duration pulse test used to minimize self-heating effect.<br/>8. Guaranteed by design. Not subject to product testing.



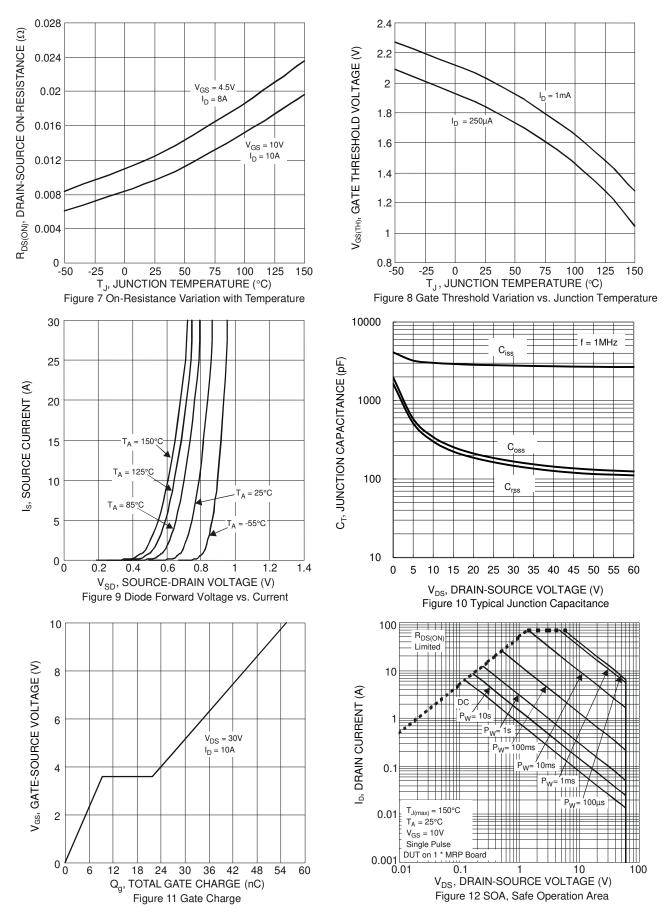
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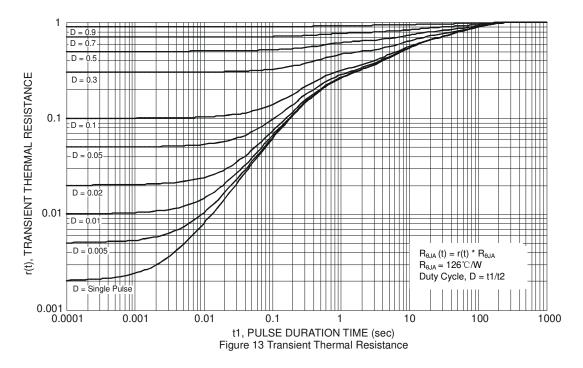


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DMN6013LFGQ Document number: DS38870 Rev. 3 - 2

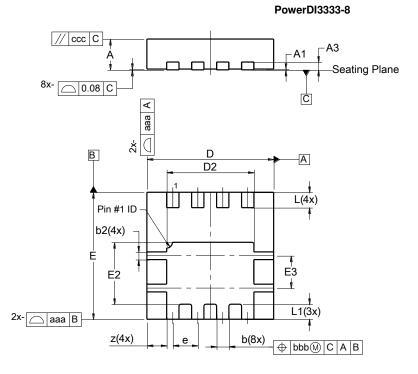






# **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

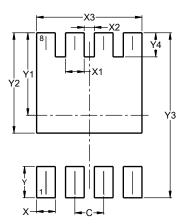


PowerDI3333-8							
		DI3333-	-				
Dim	Min	Max	Тур				
Α	0.75	0.85	0.80				
A1	0.00	0.05	0.02				
A3	-	-	0.203				
b	0.27	0.37	0.32				
b2	-	-	0.20				
D	3.25	3.35	3.30				
D2	2.22	2.32	2.27				
ш	3.25	3.35	3.30				
E2	1.56	1.66	1.61				
E3	0.79	0.89	0.84				
e	-	-	0.65				
L	0.35	0.45	0.40				
L1	-	-	0.39				
z	-	-	0.515				
aaa	0.25						
bbb		0.10					
CCC		0.10					
All I	Dimens	sions ir	n mm				

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### PowerDI3333-8



Dimensions	Value (in mm)
С	0.650
Х	0.420
X1	0.420
X2	0.230
X3	2.370
Y	0.700
Y1	1.850
Y2	2.250
Y3	3.700
Y4	0.540



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